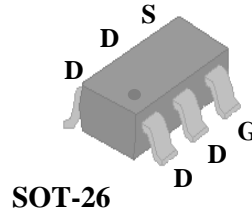
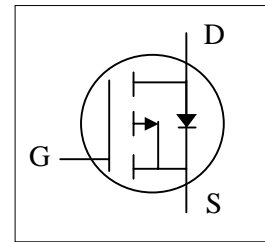




- ▼ Capable of 1.8V Gate Drive
- ▼ Small Package Outline
- ▼ Surface Mount Device
- ▼ RoHS Compliant & Halogen-Free



BV_{DSS}	-20V
$R_{DS(ON)}$	38m Ω
I_D^3	-6A



Description

AP2P038 series are from Advanced Power innovated design and silicon process technology to achieve the lowest possible on-resistance and fast switching performance. It provides the designer with an extreme efficient device for use in a wide range of power applications.

The special design SOT-26 package with good thermal performance is widely preferred for all commercial-industrial surface mount applications using infrared reflow technique and suited for voltage conversion or switch applications.

Absolute Maximum Ratings @ $T_J=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	-20	V
V_{GS}	Gate-Source Voltage	+8	V
$I_D @ T_A=25^\circ\text{C}$	Drain Current ³ , V_{GS} @ 4.5V	-6	A
$I_D @ T_A=70^\circ\text{C}$	Drain Current ³ , V_{GS} @ 4.5V	-4.8	A
I_{DM}	Pulsed Drain Current ¹	-20	A
$P_D @ T_A=25^\circ\text{C}$	Total Power Dissipation	2	W
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ\text{C}$

Thermal Data

Symbol	Parameter	Value	Unit
Rthj-amb	Maximum Thermal Resistance, Junction-ambient ³	62.5	$^\circ\text{C}/\text{W}$



AP2P038Y

Electrical Characteristics @T_j=25°C(unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =-250uA	-20	-	-	V
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =-4.5V, I _D =-4A	-	-	38	mΩ
		V _{GS} =-2.5V, I _D =-3A	-	-	50	mΩ
		V _{GS} =-1.8V, I _D =-1A	-	-	64	mΩ
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =-250uA	-0.3	-	-1	V
g _{fs}	Forward Transconductance	V _{DS} =-5V, I _D =-4A	-	15	-	S
I _{DSS}	Drain-Source Leakage Current	V _{DS} =-16V, V _{GS} =0V	-	-	-10	uA
I _{GSS}	Gate-Source Leakage	V _{GS} =±8V, V _{DS} =0V	-	-	±0.1	uA
Q _g	Total Gate Charge	I _D =-4A	-	14.5	23.2	nC
Q _{gs}	Gate-Source Charge	V _{DS} =-10V	-	3	-	nC
Q _{gd}	Gate-Drain ("Miller") Charge	V _{GS} =-4.5V	-	3.5	-	nC
t _{d(on)}	Turn-on Delay Time	V _{DS} =-10V	-	10	-	ns
t _r	Rise Time	I _D =-1A	-	17	-	ns
t _{d(off)}	Turn-off Delay Time	R _G =3.3Ω	-	47	-	ns
t _f	Fall Time	V _{GS} =-5V	-	27	-	ns
C _{iss}	Input Capacitance	V _{GS} =0V	-	1450	2320	pF
C _{oss}	Output Capacitance	V _{DS} =-10V	-	180	-	pF
C _{rss}	Reverse Transfer Capacitance	f=1.0MHz	-	135	-	pF

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V _{SD}	Forward On Voltage ²	I _S =-1.2A, V _{GS} =0V	-	-	-1.2	V
t _{rr}	Reverse Recovery Time	I _S =-4A, V _{GS} =0V,	-	11	-	ns
Q _{rr}	Reverse Recovery Charge	dI/dt=100A/μs	-	4	-	nC

Notes:

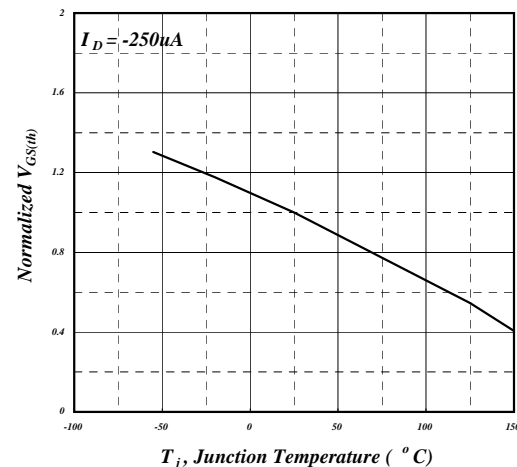
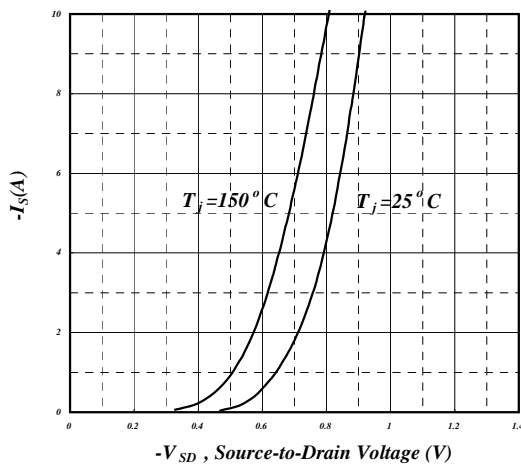
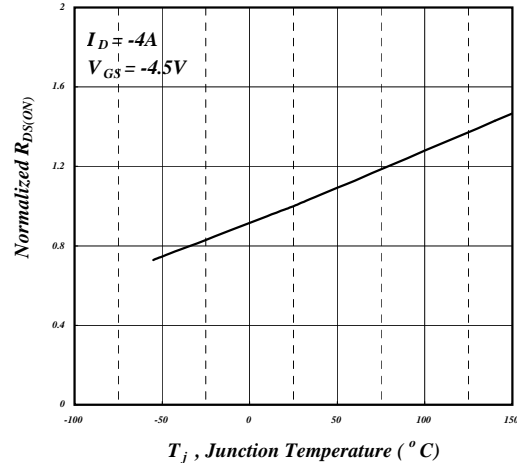
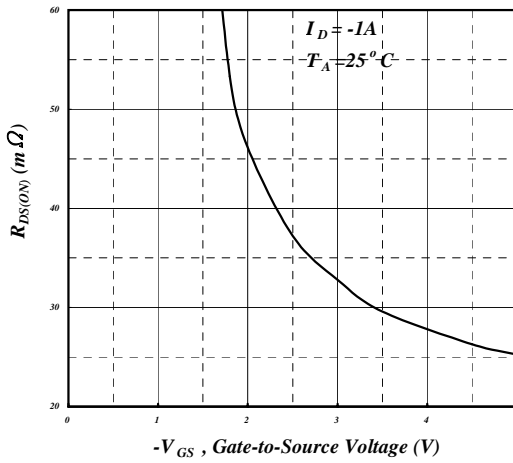
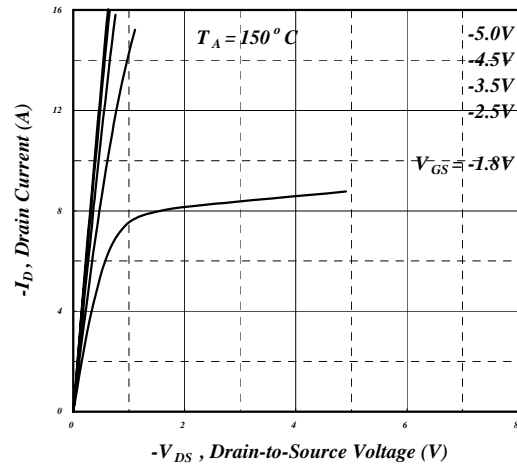
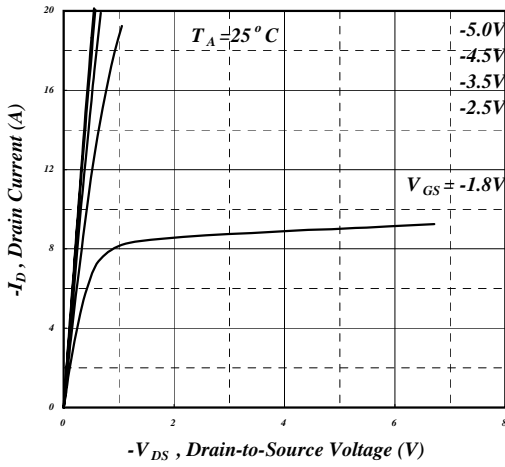
- 1.Pulse width limited by Max. junction temperature.
- 2.Pulse test
- 3.Surface mounted on 1 in² copper pad of FR4 board, t ≤ 10sec ; 156°C/W when mounted on min. copper pad.

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.

USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT, AUTOMOTIVE OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.

APEC DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

APEC RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN.



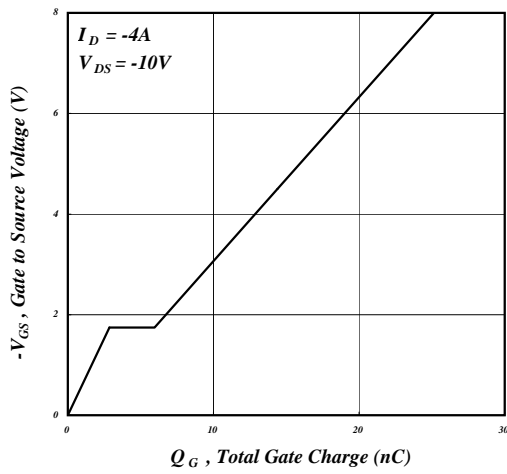


Fig 7. Gate Charge Characteristics

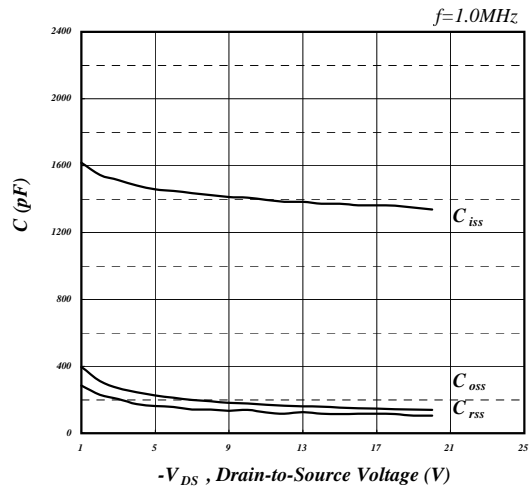


Fig 8. Typical Capacitance Characteristics

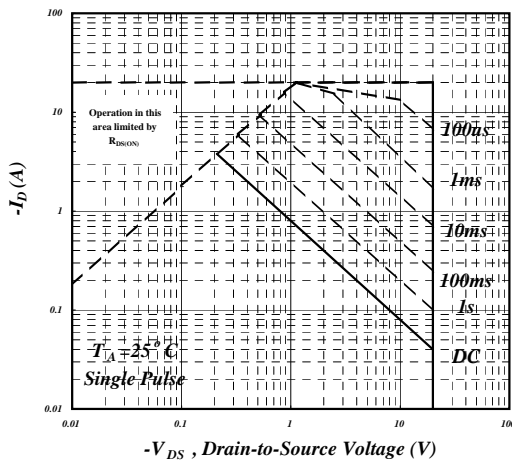


Fig 9. Maximum Safe Operating Area

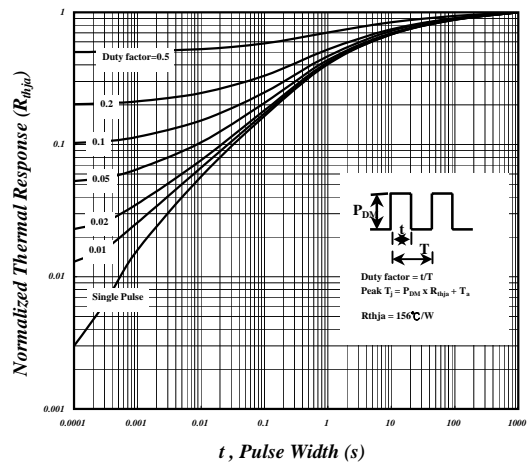


Fig 10. Effective Transient Thermal Impedance

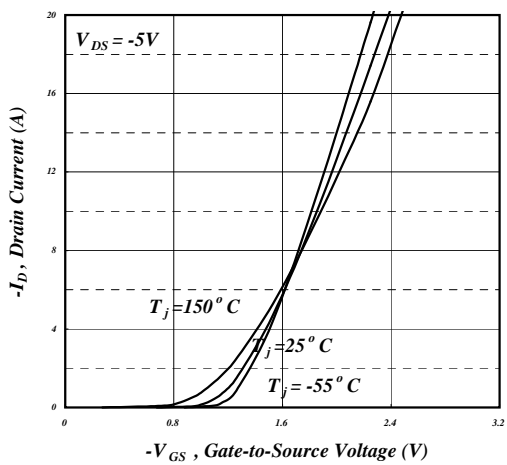


Fig 11. Transfer Characteristics

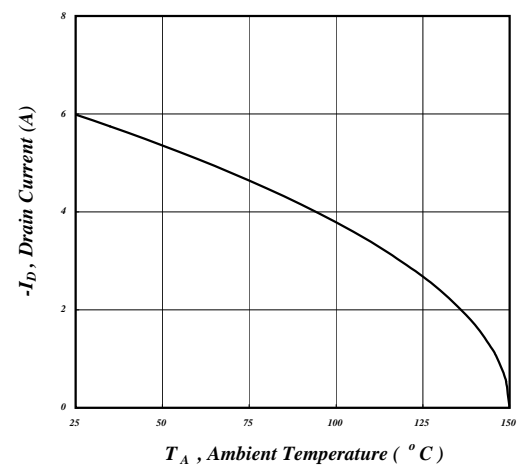


Fig 12. Drain Current v.s. Ambient Temperature

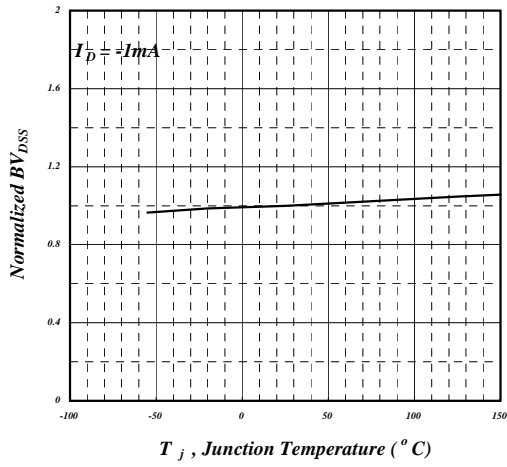


Fig 13. Normalized BV_{DSS} v.s. Junction Temperature

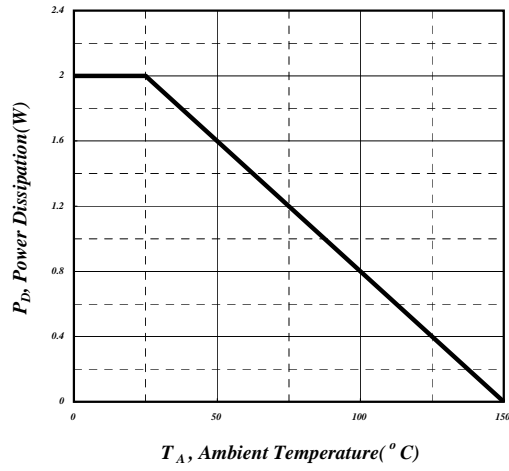
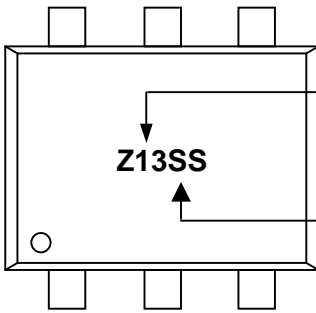


Fig 14. Total Power Dissipation



AP2P038Y

MARKING INFORMATION



Part Number : Z13

Date Code : SS

SS:2004,2008,2012,2016,2020...

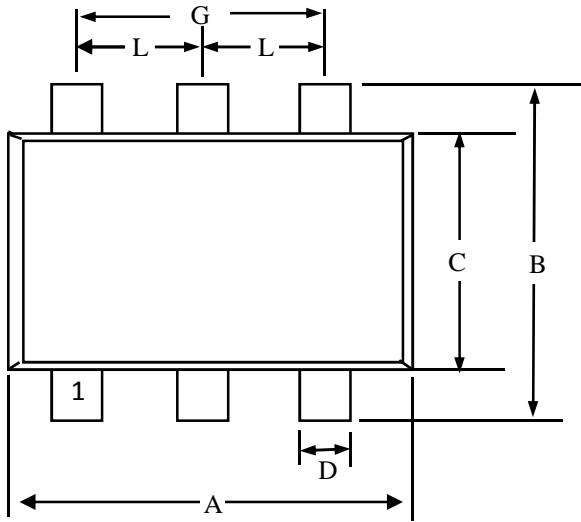
SS:2003,2007,2011,2015,2019...

SS:2002,2006,2010,2014,2018...

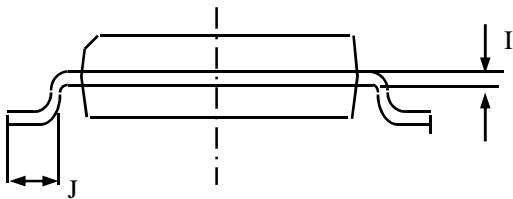
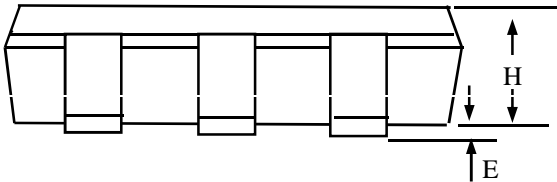
SS:2001,2005,2009,2013,2017...



Package Outline : SOT-26



SYMBOLS	Millimeters		
	MIN	NOM	MAX
A	2.70	2.90	3.10
B	2.60	2.80	3.00
C	1.40	1.60	1.80
D	0.30	0.40	0.50
E	0.00	0.05	0.10
H	1.00	1.15	1.30
G	—	1.95 (ref.)	—
I	0.10	0.15	0.20
J	0.30	0.45	0.60
L	—	0.95 (ref.)	—



- 1.All Dimension Are In Millimeters.
- 2.Dimension Does Not Include Mold Protrusions.



SOT-26 FOOTPRINT :

